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APPLICATION NUMBER	ATION NUMBER FILING DATE		FIRST NAMED APPLICANT	ATTORI	ATTORNEY DOCKET NO.	
09/132,157	08/11/98	FORBES		L 3	03.229US2	
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	n from the examiner in ch PATENTS AND TRADEM		plication.			
			CTION SUMMARY			
Responsive to commun	nication(s) filed on	10/+/	98		<u>-</u>	
☐ This action is FINAL.						
Since this application is accordance with the pro-	in condition for allow actice under Ex parte	ance except i <i>Quayle</i> , 1935	for formal matters, prosecu D.C. 11; 453 O.G. 213.	ition as to the mer	its is closed in	
A shortened statutory period whichever is longer, from the application to become a 1.136(a).	he mailing date of this	communicati	on. Failure to respond wit	hin the period for re	sponse will cause	
Disposition of Claims	1 01					
Claim(s)	14 and 24	<u>1-3+</u>		is/are pe	ending in the application	
Of the above, claim(s	;)			is/are withdr	awn from consideratio	
Claim(s)					is/are allowed.	
Claim(s)	14 and 2	4-37	-		is/are rejected.	
Claim(s)	·	\$		×	_ is/are objected to.	
Claims			are s	subject to restriction	or election requireme	
Application Papers						
See the attached Not	tice of Draftsperson's	Patent Drawii	ng Review, PTO-948.			
☐ The drawing(s) filed o	on		is/are object	cted to by the Exam	iner.	
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☐ The oath or declaration						
Priority under 35 U.S.C.						
☐ Acknowledgement is m	-	aian nriority ur	nder 35 U.S.C. & 119(a)-(d	N		
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Notice of Reference	Cited PTC 999	•				
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Notice of Informal Pa	tent Application, PTO	-152				

This Office Action is in response to the "Second Preliminary Amendment" filed October 7, 1998 and supersedes the Office Action mailed October 27, 1998 (although that previous Office Action's attachments are incorporated herein).

Claims 11-14, 24, 26, 28-31 and 33-35 are rejected under 35 U.S.C. §102(b) as anticipated by Nayak et al. (IEEE Electron Device Letters, Vol. 12, No. 4, April 1991, pages 154-156). See the entire reference.

Claims 25, 32 and 37 are rejected under 35 U.S.C. §102(b) as anticipated by or, in the alternative, under 35 U.S.C. §103 as obvious over Nayak et al. (IEEE Electron Device Letters, Vol. 12, No. 4, April 1991, pages 154-156). See the entire reference. Note that a device claim's process limitations are not determinative of patentability. See *In re Thorpe*, 227 USPQ 964 (Fed. Cir. 1985).

Claims 30 and 31 are rejected under 35 U.S.C. §102(b) as anticipated by Sato et al. (United States Patent 5,285,088). See the entire patent.

Claims 32 and 37 are rejected under 35 U.S.C. §102(b) as anticipated by or, in the alternative, under 35 U.S.C. §103 as obvious over Sato et al. (United States Patent 5,285,088). See the entire patent. Note that a device claim's process limitations are not determinative of patentability. See *In re Thorpe*, 227 USPQ 964 (Fed. Cir. 1985).

Claims 11, 14, 24, 28 and 30 are rejected under 35 U.S.C. §102(b) as anticipated by Selvakumar et al. (United States Patent 5,426,069). See Selvakumar et al's Figs. 1-7 embodiment in particular.

Claims 25, 32 and 37 are rejected under 35 U.S.C. §102(b) as anticipated by or, in the alternative, under 35 U.S.C. §103 as obvious over Selvakumar et al. (United States Patent 5,426,069). See Selvakumar et al's Figs. 1-7 embodiment in particular. Note that a device claim's process limitations are not determinative of patentability.

See In re Thorpe, 227 USPQ 964 (Fed. Cir. 1985).

Claims 30, 31, 33 and 34 are rejected under 35 U.S.C. §102(e) as anticipated by Crabbe' et al. (United States Patent 5,821,577). See the entire patent.

Claims 32 and 37 are rejected under 35 U.S.C. §102(e) as anticipated by or, in the alternative, under 35 U.S.C. §103 as obvious over Crabbe' et al. (United States Patent 5,821,577). See the entire patent. Note that a device claim's process limitations are not determinative of patentability. See *In re Thorpe*, 227 USPQ 964 (Fed. Cir. 1985).

Claims 12-13, 26, 27, 29, 31 and 33-35 are rejected under 35 U.S.C. §103 as being unpatentable over Selvakumar et al. (United States Patent 5,426,069) together with Crabbe' et al. (United States Patent 5,821,577).

With respect to dependent claims 12, 29 and 33-35, the difference between their transistor and Selvakumar et al's transistor is that they are p-type and n-type, respectively. Crabbe' et al. illustrates a p-type SiGe channel transistor. It would have been obvious to one skilled in this art to extend Selvakumar et al's SiGe disclosure to a p-type transistor as suggested by Crabbe' et al.. Claims 12, 29 and 33-35 are thus rejected under 35 U.S.C. §103 as being unpatentable over Selvakumar et al. together with Crabbe' et al..

With respect to dependent claims 13, 26, 27 and 31, the difference between their transistor and Selvakumar et al's transistor is that the latter's SiGe channel thickness is unknown while the former's SiGe channel thickness is "approximately 100 to 1,000 angstroms" (claims 13, 26 and 31) or "approximately 300 angstroms" (claim 27). Crabbe' et al. discloses forming SiGe channels 100 to 500 angstroms thick (see column 6, lines 17-22). It would have been obvious to one skilled in this art to

make Selvakumar et al's SiGe channel 100 to 500 angstroms thick as suggested by Crabbe' et al.. Claims 13, 26, 27 and 31 are thus rejected under 35 U.S.C. §103 as being unpatentable over Selvakumar et al. together with Crabbe' et al..

Claims 11, 12, 14, 24, 25, 28-30, 32-34, 36 and 37 are rejected under 35 U.S.C. §103 as being unpatentable over Maeda et al. (United States Patent 5,512,772) together with Selvakumar et al. (United States Patent 5,426,069). Specifically, the difference between Maeda et al. (see Figure 1's transistor M2) and the set of rejected claims is their channels comprise Si and SiGe, respectively. Selvakumar et al. teaches SiGe channels (see Selvakumar et al's Figures 1-7 embodiment in particular). It would have been obvious to one skilled in this art to provide Maeda et al's transistor M2 with a SiGe channel to enhance its performance as taught by Selvakumar et al.. Claims 11, 12, 14, 24, 25, 28-30, 32-34, 36 and 37 are thus rejected under 35 U.S.C. §103 as being unpatentable over Maeda et al. together with Selvakumar et al..

Claims 13, 26, 27 and 31 are rejected under 35 U.S.C. §103 as being unpatentable over Maeda et al. (United States Patent 5,512,772) together with Selvakumar et al. (United States Patent 5,426,069) and Crabbe' et al. (United States Patent 5,821,577). Specifically, the difference between the obvious Maeda et al. / Selvakumar et al. device (discussed above) and the set of rejected claims is that the latter's SiGe channel thickness is unknown while the former's SiGe channel thickness is "approximately 100 to 1,000 angstroms" (claims 13, 26 and 31) or "approximately 300 angstroms" (claim 27). Crabbe' et al. discloses forming SiGe channels 100 to 500 angstroms thick (see column 6, lines 17-22). It would have been obvious to one skilled in this art to make the obvious Maeda et al. / Selvakumar et al. device's SiGe channel 100 to 500 angstroms thick as suggested by Crabbe' et al.. Claims 13, 26, 27

and 31 are thus rejected under 35 U.S.C. §103 as being unpatentable over Maeda et al. together with Selvakumar et al. and Crabbe' et al..

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